

1. DESCRIPTION

The XB431 is precision 1.24 V shunt regulators capable of adjustment to 30 V. Negative feedback from the cathode to the adjust pin controls the cathode voltage, much like a non-inverting op amp configuration (Refer to Symbol and Functional Diagrams). A two-resistor voltage divider terminated at the adjust pin controls the gain of a 1.24 V band-gap reference. Shorting the cathode to the adjust pin (voltage follower) provides a cathode voltage of a 1.24 V.

The XB431 have respective initial tolerances of 1.5%, and functionally lend themselves to several applications that require zener diode type performance at low voltages. Applications include a 3 V to 2.7 V low drop-out regulator, an error amplifier in a 3 V off-line switching regulator and even as a voltage detector. These parts are typically stable with capacitive loads greater than 10 nF and less than 50 pF.

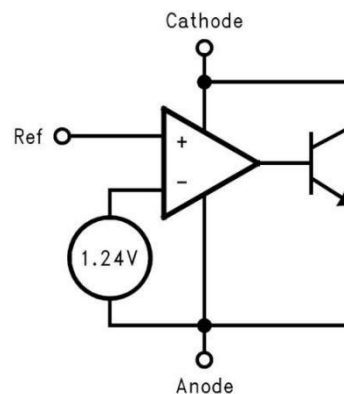
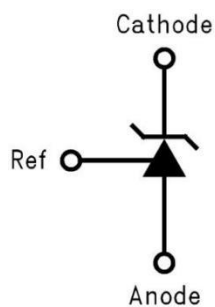
2. FEATURES

- Low-Voltage Operation/Wide Adjust Range (1.24 V/30 V)
- Temperature Compensated for Industrial
- Low Operation Current (55 μ A)
- Low Output Impedance (0.25 Ω)
- Fast Turn-On Response

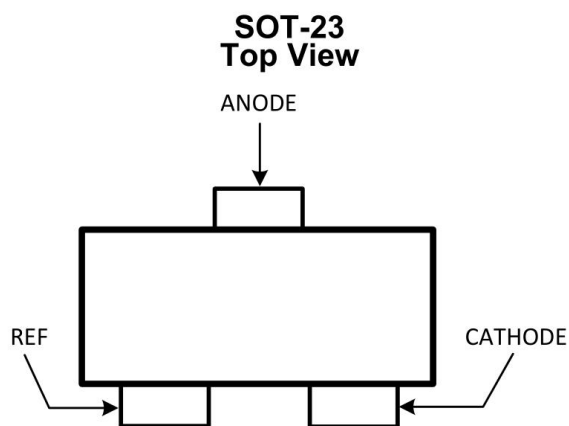
3. APPLICATIONS

- Shunt Regulator
- Series Regulator
- Current Source or Sink
- Voltage Monitor
- Error Amplifier
- 3-V Off-Line Switching Regulator
- Low Dropout N-Channel Series Regulator

4. SYMBOL AND FUNCTIONAL DIAGRAMS



5. PIN CONFIGURATIONS AND FUNCTIONS



6. SPECIFICATIONS

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Operating temperature	Commercial (XB431)	0	70	°C
Lead temperature	SOT-23 -5,-3 Package (Soldering, 10 sec.)		265	
Internal power dissipation ⁽²⁾	SOT-23-5, -3 Package		0.28	W
Cathode voltage			35	V
Continuous cathode current		-30	30	mA
Reference input current		-.05	3	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Ratings apply to ambient temperature at 25°C. Above this temperature, derate the SOT-23-3at 2.2 mW/°C. See derating curve in Operating Condition section.

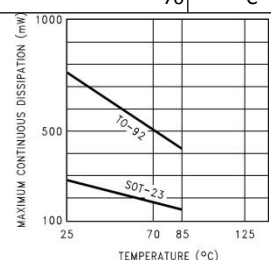
6.2 Handling Ratings

		MIN	MAX	UNIT
T _{stg}	Storage temperature range	-65	150	°C
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾		2000 V

- (1) The human body model is a 100 pF capacitor discharged through a 1.5kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Cathode voltage		V _{REF}		30	V
Cathode current		0.1		15	mA
Temperature	XB431	0		70	°C
Derating Curve (Slope = -1/R _{θJA})					

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		XB431	UNIT
		SOT-23	
		3 PINS	
R _{θJA}	Junction-to-ambient thermal resistance ⁽²⁾	455	°C/W

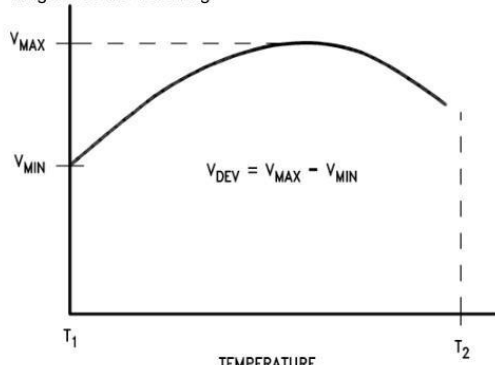
- (1) T_{J Max} = 150°C, T_J = T_A + (R_{θJA} P_D), where P_D is the operating power of the device.

6.5 XB431-LM Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REF}	Reference Voltage	$V_Z = V_{REF}, I_Z = 10\text{ mA}$ $T_A = 25^\circ\text{C}$ $T_A = \text{Full Range}$	1.222 1.21	1.24	1.258 1.27	V
V_{DEV}	Deviation of Reference Input Voltage Over Temperature ⁽¹⁾	$V_Z = V_{REF}, I_Z = 10\text{ mA}$ $T_A = \text{Full Range}$		4	12	mV
$\frac{\Delta V_{REF}}{\Delta V_Z}$	Ratio of the Change in Reference Voltage to the Change in Cathode Voltage	$I_Z = 10\text{ mA}$ V_Z from V_{REF} to 6 V $R_1 = 10\text{ k}\Omega, R_2 = \infty$ and 2.6 k Ω		-1.5	-2.7	mV/V
I_{REF}	Reference Input Current	$R_1 = 10\text{ k}\Omega, R_2 = \infty$ $I_I = 10\text{ mA}$		0.15	0.5	μA
∞I_{REF}	Deviation of Reference Input Current over Temperature	$R_1 = 10\text{ k}\Omega, R_2 = \infty$ $I_I = 10\text{ mA}, T_A = \text{Full Range}$		0.05	0.3	μA
$I_{Z(MIN)}$	Minimum Cathode Current for Regulation	$V_Z = V_{REF}$		55	80	μA
$I_{Z(OFF)}$	Off-State Current	$V_Z = 6\text{ V}, V_{REF} = 0\text{ V}$		0.001		μA
r_Z	Dynamic Output Impedance ⁽²⁾	$V_Z = V_{REF}, I_Z = 0.1\text{ mA to }15\text{ mA}$ Frequency = 0 Hz		0.25	0.4	Ω

- (1) Deviation of reference input voltage, V_{DEV} , is defined as the maximum variation of the reference input voltage over the full temperature range. See the following:



The average temperature coefficient of the reference input voltage, ∞V_{REF} , is defined as:

$$\infty V_{REF} \frac{\text{ppm}}{^\circ\text{C}} = \frac{\pm \left(\frac{V_{MAX} - V_{MIN}}{V_{REF}(\text{at } 25^\circ\text{C})} \right) 10^6}{T_2 - T_1} = \frac{\pm \left(\frac{V_{DEV}}{V_{REF}(\text{at } 25^\circ\text{C})} \right) 10^6}{T_2 - T_1}$$

Where: $T_2 - T_1$ = full temperature change. ∞V_{REF} can be positive or negative depending on whether the slope is positive or negative.
Example: $V_{DEV} = 6\text{ mV}$, $V_{REF} = 1240\text{ mV}$, $T_2 - T_1 = 125^\circ\text{C}$.

$$\infty V_{REF} = \frac{\left(\frac{6.0\text{ mV}}{1240\text{ mV}} \right) 10^6}{125^\circ\text{C}} = +39\text{ ppm} / ^\circ\text{C}$$

- (2) The dynamic output impedance, r_Z , is defined as:

$$r_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R_1 and R_2 , see Figure 31 the dynamic output impedance of the overall circuit, r_Z , is defined as:

$$r_Z = \frac{\Delta V_Z}{\Delta I_Z} \cong \left[r_Z \left(1 + \frac{R_1}{R_2} \right) \right]$$

6.6 Typical Performance Characteristics

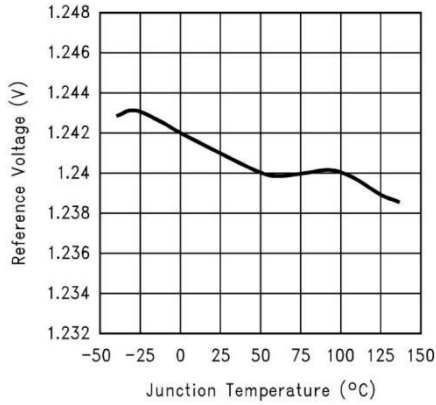


Figure 1. Reference Voltage vs. Junction Temperature

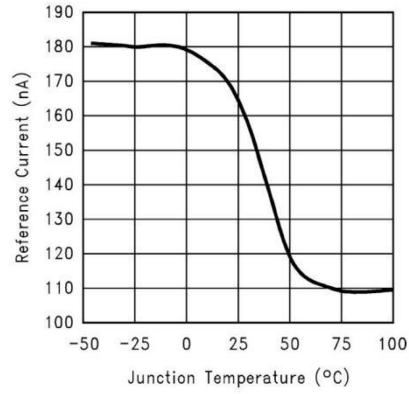


Figure 2. Reference Input Current vs. Junction Temperature

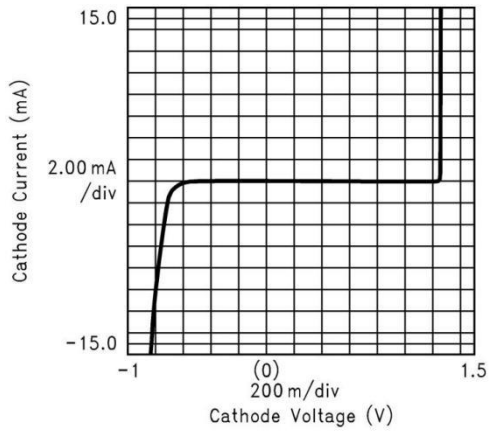


Figure 3. Cathode Current vs. Cathode Voltage 1

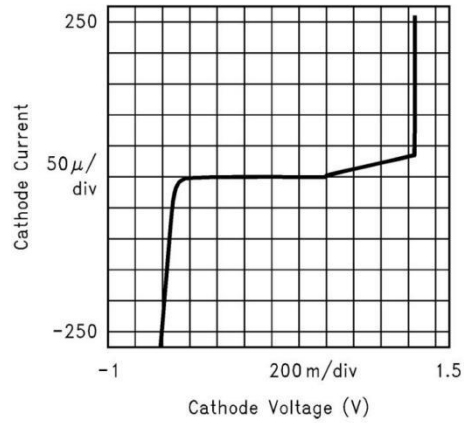


Figure 4. Cathode Current vs. Cathode Voltage 2

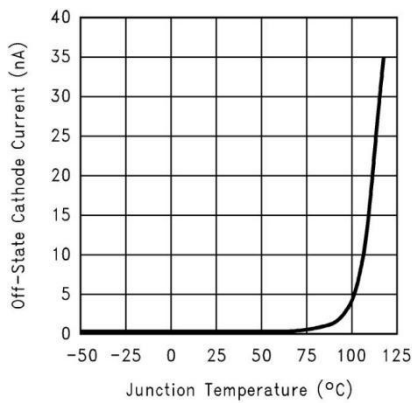


Figure 5. Off-State Cathode Current vs. Junction Temperature

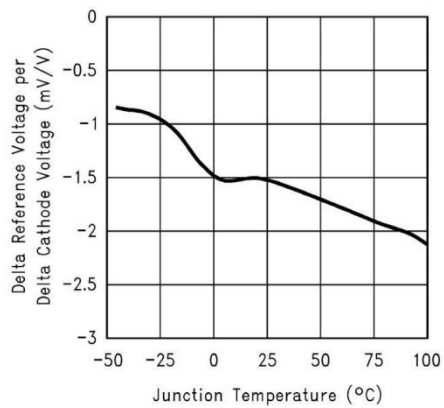


Figure 6. Delta Reference Voltage Per Delta Cathode Voltage vs. Junction Temperature

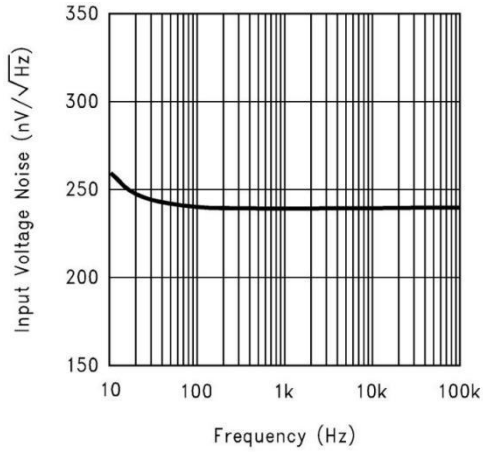


Figure 7. Input Voltage Noise vs. Frequency

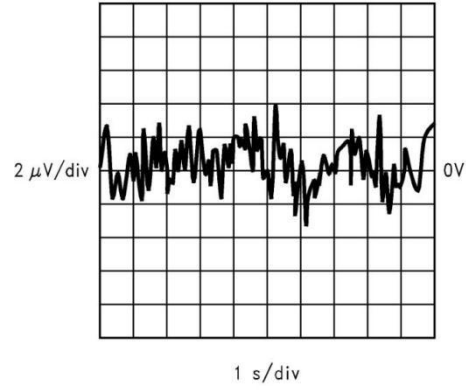


Figure 8. Low Frequency Peak To Peak Noise

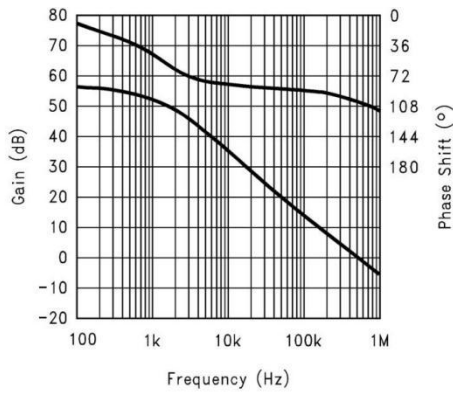


Figure 9. Small Signal Voltage Gain And Phase Shift vs. Frequency

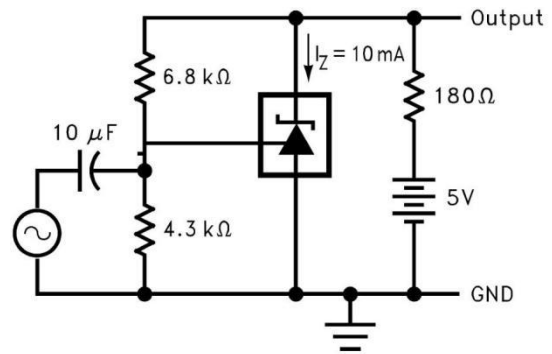


Figure 10. Test Circuit For Voltage Gain And Phase Shift vs. Frequency

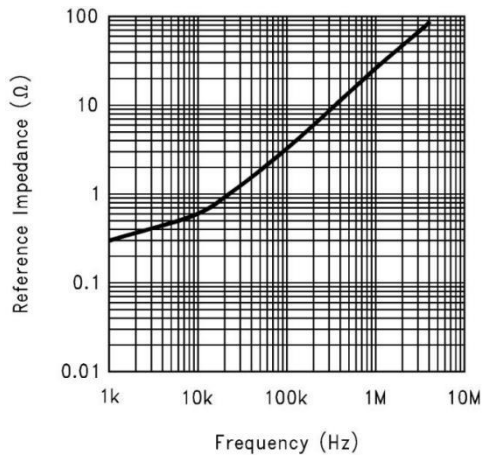


Figure 11. Reference Impedance vs. Frequency

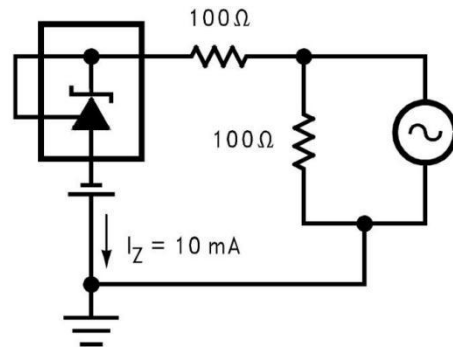


Figure 12. Test Circuit For Reference Impedance vs. Frequency

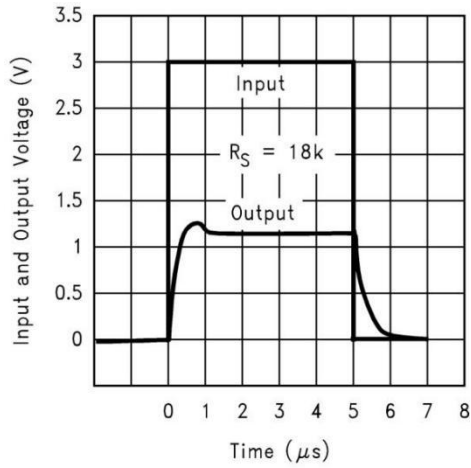


Figure 13. Pulse Response 1

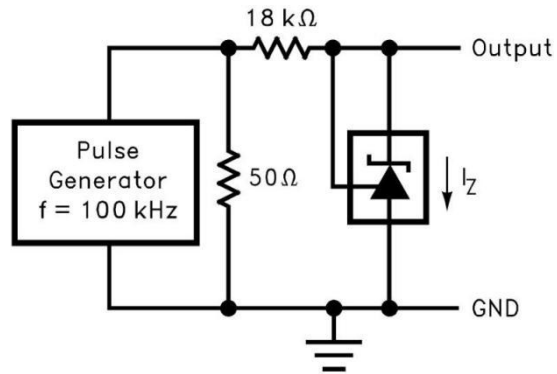


Figure 14. Test Circuit For Pulse Response 1

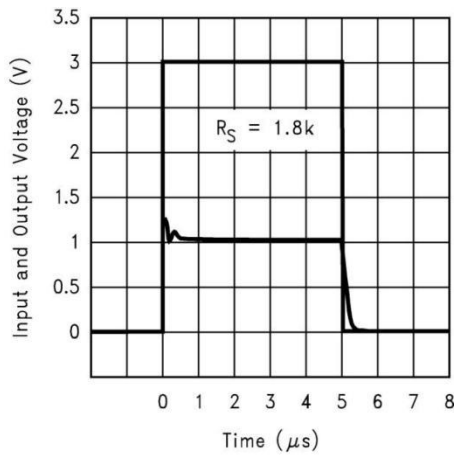


Figure 15. Pulse Response 2

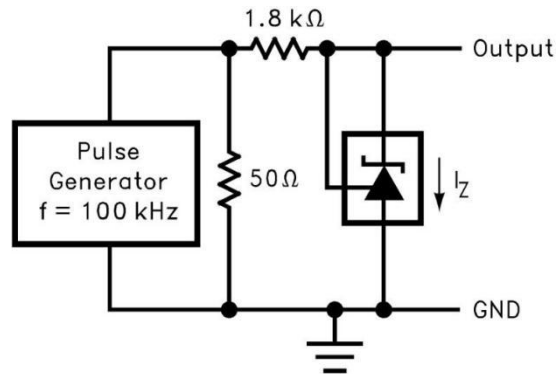


Figure 16. Test Circuit For Pulse Response 2

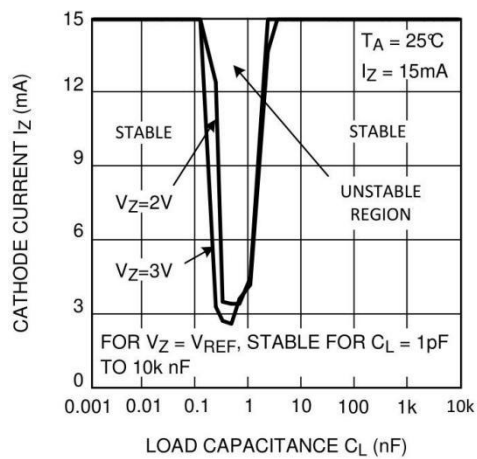


Figure 17. XB431 Stability Boundary Condition

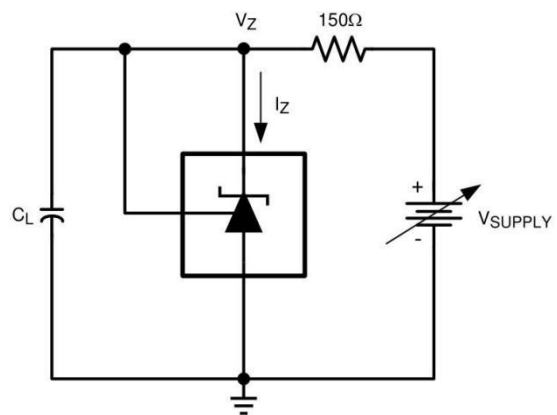


Figure 18. Test Circuit For $V_Z = V_{\text{REF}}$

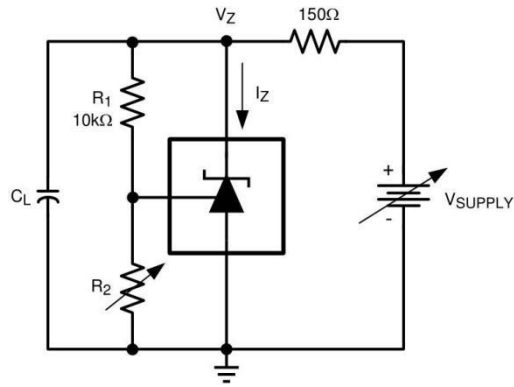
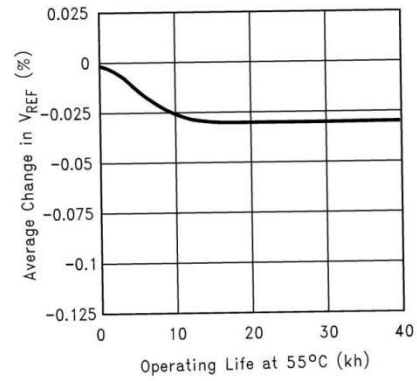


Figure 19. Test Circuit For $V_Z = 2V, 3V$

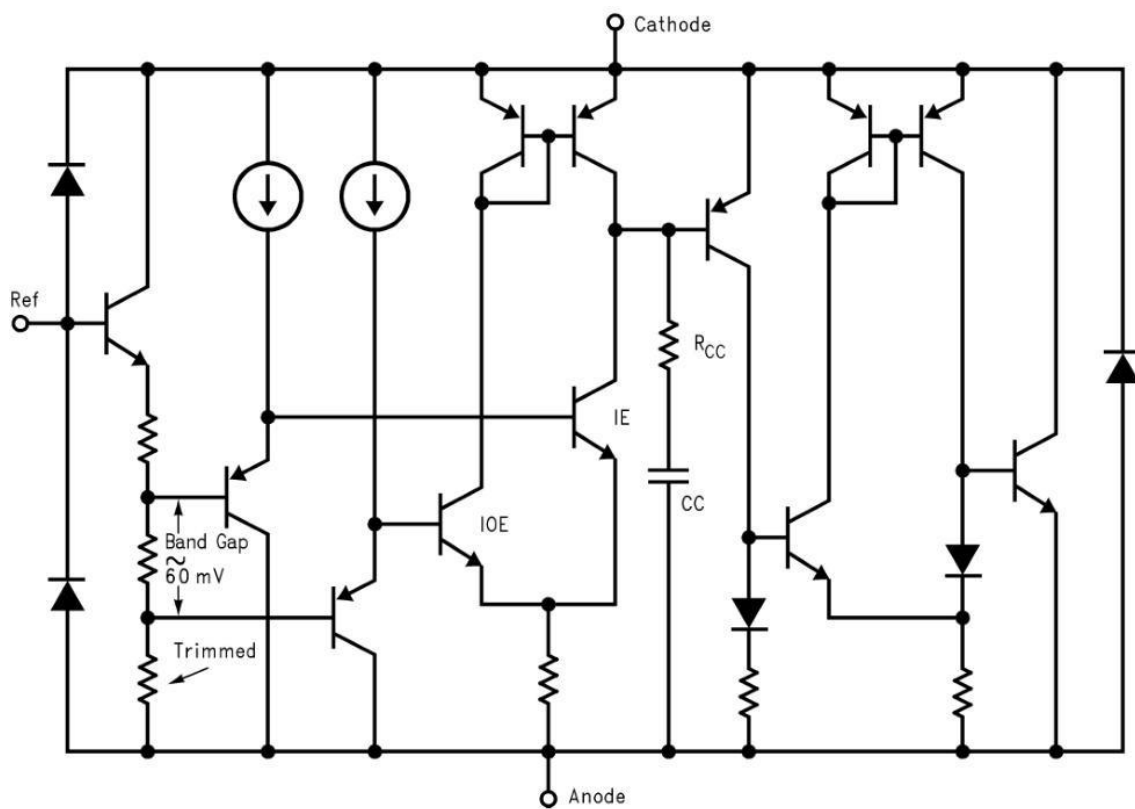


Extrapolated from life-test data taken at 125°C; the activation energy assumed is 0.7eV.

Figure 20. Percentage Change In V_{REF} vs. Operating Life At 55°C

7. DETAILED DESCRIPTION

7.1 Functional Block Diagram



8. APPLICATION AND IMPLEMENTATION

NOTE

Information in the following applications sections is not part of the XINLUDA component specification, and XINLUDA does not warrant its accuracy or completeness. XINLUDA's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Typical Application

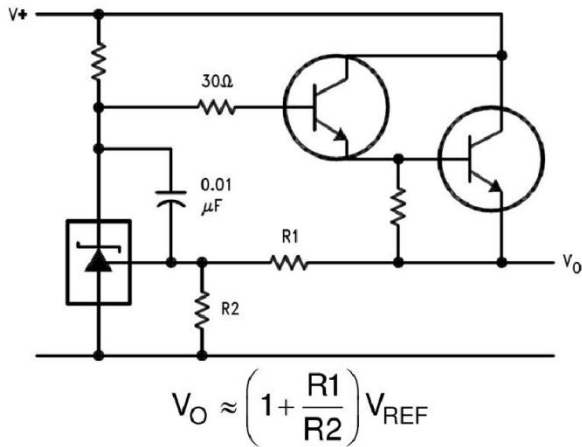


Figure 21. Series Regulator

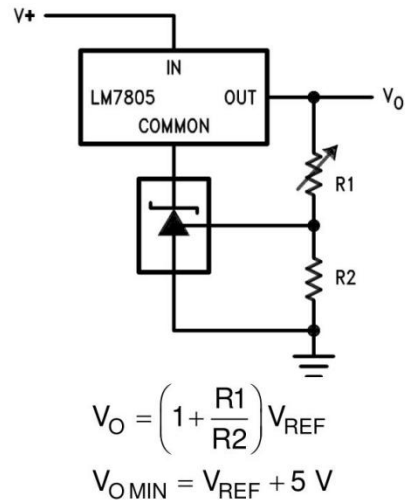


Figure 22. Output Control of a Three-Terminal Fixed Regulator

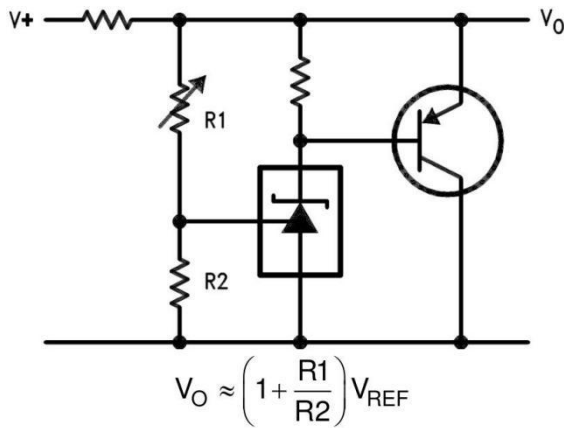


Figure 23. Higher Current Shunt Regulator

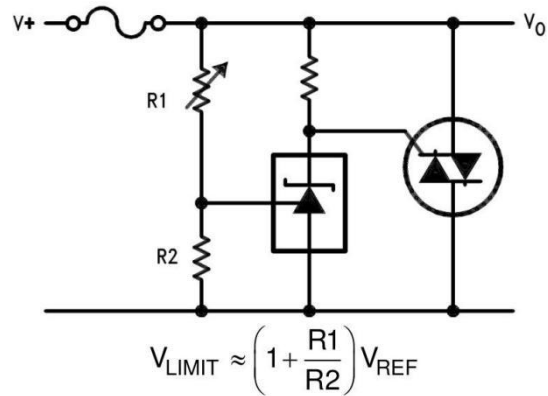
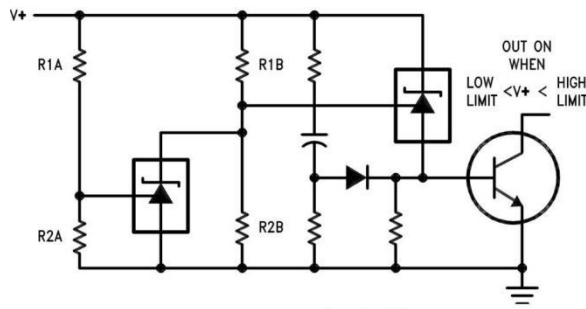


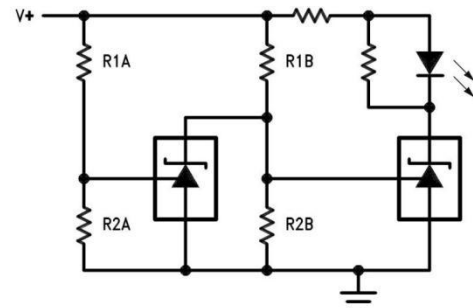
Figure 24. Crow Bar



$$\text{LOW LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1B}{R2B} \right) + V_{\text{BE}}$$

$$\text{HIGH LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1A}{R2A} \right)$$

Figure 25. Overvoltage/Undervoltage Protection Circuit

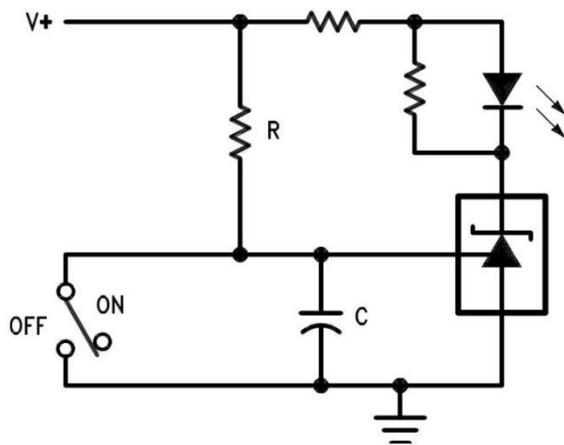


$$\text{LOW LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1B}{R2B} \right) \quad \text{LED ON WHEN}$$

$$\text{HIGH LIMIT} \approx V_{\text{REF}} \left(1 + \frac{R1A}{R2A} \right)$$

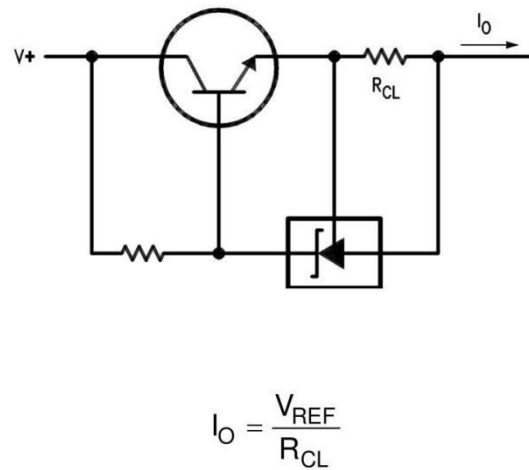
LOW LIMIT < V+ < HIGH LIMIT

Figure 26. Voltage Monitor



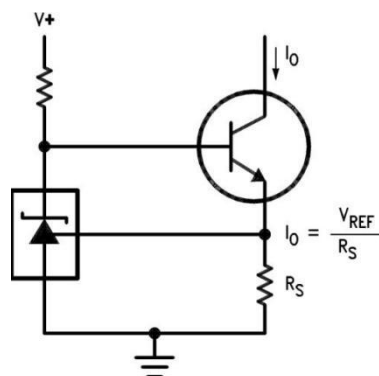
$$\text{DELAY} = R \cdot C \cdot \ln \frac{V+}{(V+) - V_{\text{REF}}}$$

Figure 27. Delay Timer



$$I_O = \frac{V_{\text{REF}}}{R_{\text{CL}}}$$

Figure 28. Current Limiter or Current Source



$$I_O = \frac{V_{\text{REF}}}{R_S}$$

Figure 29. Constant Current Sink

8.2 DC/AC Test Circuit

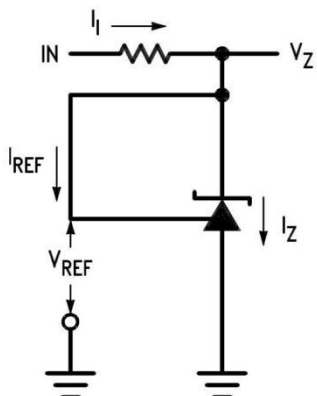


Figure 30. Test Circuit For $V_Z = V_{REF}$

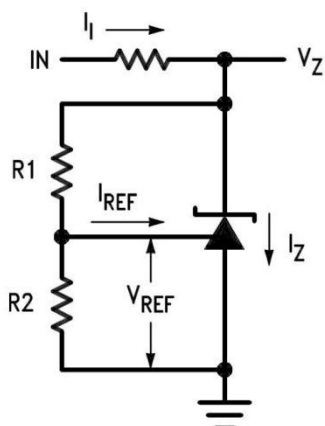


Figure 31. Test Circuit For $V_Z > V_{REF}$

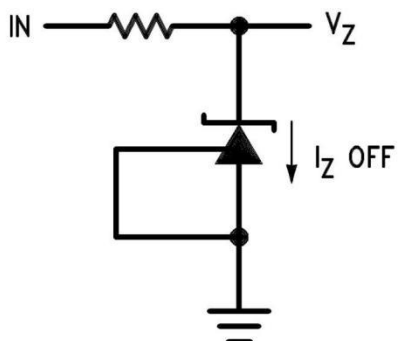


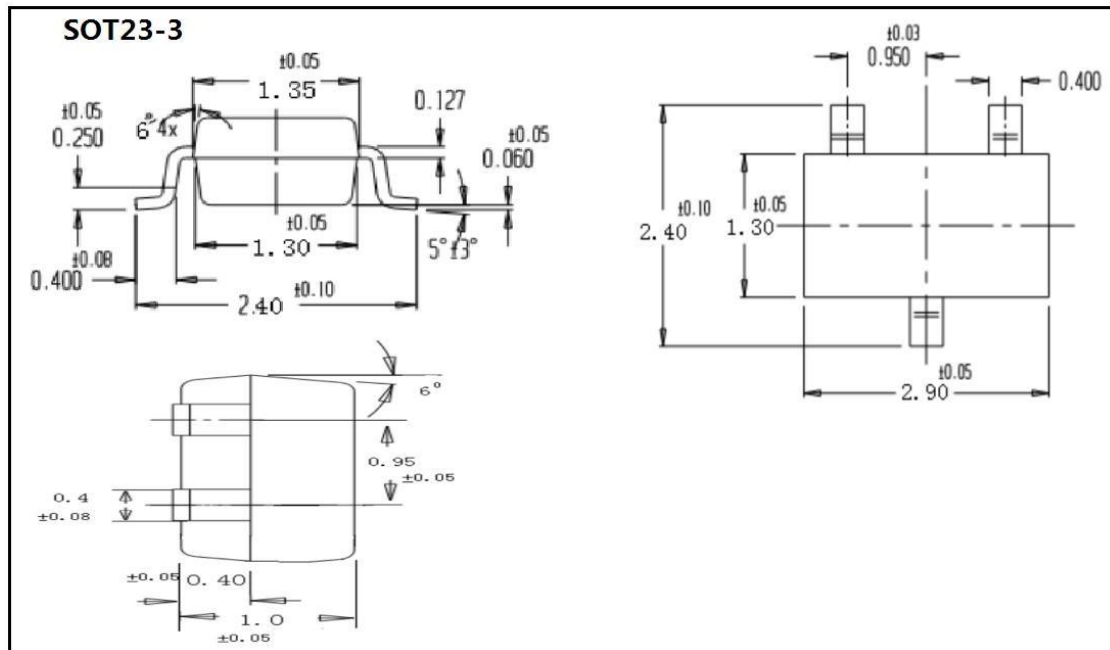
Figure 32. Test Circuit For Off-State Current

9. ORDERING INFORMATION

Ordering Information

Part Number	Device Marking	Package Type	Body size (mm)	Temperature (°C)	MSL	Transport Media	Package Quantity
XB431-LM	RLA	SOT23-3	3.00 * 1.40	- 0 to +70	MSL3	T&R	3000

10. DIMENSIONAL DRAWINGS



[if you need help contact us. Xinluda reserves the right to change the above information without prior notice]